

DMN3025LFV

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	18mΩ @ V _{GS} = 10V	25A
30V	30mΩ @ V _{GS} = 4.5V	20A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

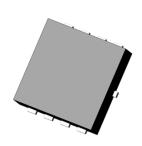
Features and Benefits

- Low R_{DS(ON)} Ensures On State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

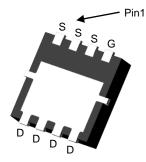
Mechanical Data

- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.072 grams (Approximate)

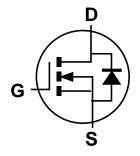
PowerDI3333-8 (Type UX)



Top View



Bottom View



Equivalent Circuit

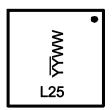
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3025LFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel
DMN3025LFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



L25= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 17 = 2017)

WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	30	V
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 7) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$		I _D	25 20	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	55	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	3	Α	
Avalanche Current, L = 0.1mH (Note 8)	I _{AS}	14	Α	
Avalanche Energy, L = 0.1mH (Note 8)		Eas	9.8	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

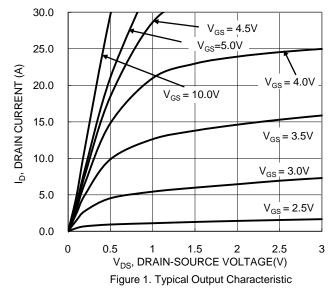
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	146	°C/W
Total Power Dissipation (Note 6)		P _D	2.2	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		$R_{ heta JA}$	57	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	4.5	C/VV
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol Min Typ Max		Unit	Test Condition			
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	>	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA $V_{DS} = 30V, V_{GS} = 0V$		
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	1.0	-	2.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Pages	-	13	18	mΩ	$V_{GS} = 10V, I_D = 7A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	21	30		$V_{GS} = 4.5V, I_{D} = 7A$	
Diode Forward Voltage	V_{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	-	500	-	рF	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	-	72	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	57	-	pF		
Gate Resistance	R_{g}	-	1.9	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_g	-	4.6	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	9.8	-	nC	V _{DS} = 15V. I _D = 10A	
Gate-Source Charge	Q _{gs}	-	1.6	-	nC	V _{DS} = 15V, I _D = 10A	
Gate-Drain Charge	Q _{gd}	-	2.0	-	nC		
Turn-On Delay Time	t _{D(ON)}	-	3.9	-	ns	$V_{DD} = 15V, V_{GS} = 10V,$ $R_g = 6\Omega, I_D = 1A$	
Turn-On Rise Time	t _R	-	4.2	-	ns		
Turn-Off Delay Time	t _{D(OFF)}	-	16.6	-	ns		
Turn-Off Fall Time	t _F	_	5.8	-	ns		
Body Diode Reverse Recovery Time	t _{RR}	-	5.6	-	ns	1 404 11/14 4004/	
Body Diode Reverse Recovery Charge	Q _{RR}	-	2.6	-	nC	$I_F = 12A$, di/dt = 100A/µs	

- Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 - 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 - 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
 - 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_{J} = +25°C.
 - 9. Short duration pulse test used to minimize self-heating effect.
 - 10. Guaranteed by design. Not subject to product testing.





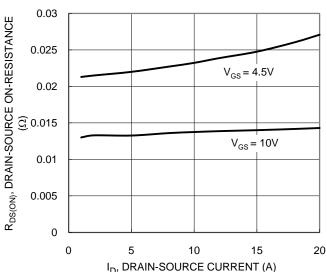


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

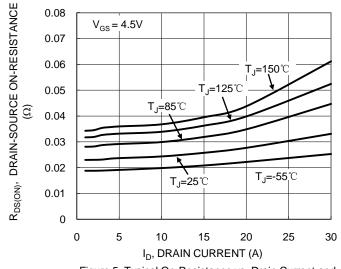


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

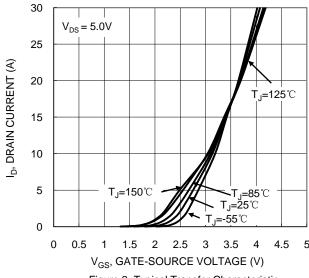


Figure 2. Typical Transfer Characteristic

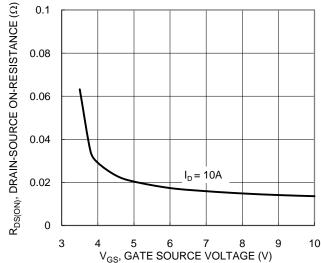


Figure 4. Typical On-Resistance vs. Drain Current and Gate Voltage

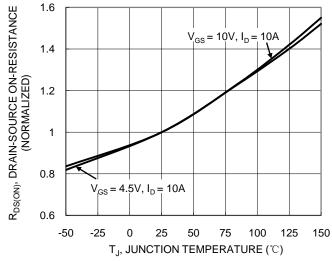


Figure 6. On-Resistance Variation with Temperature





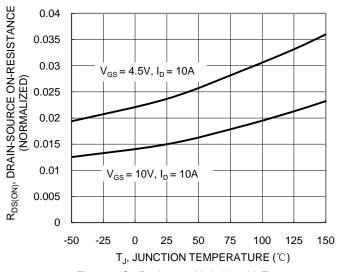
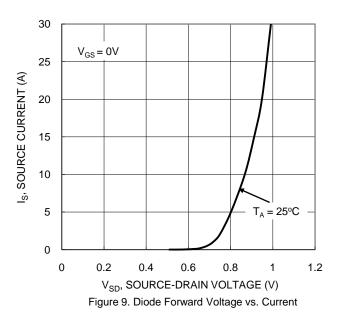
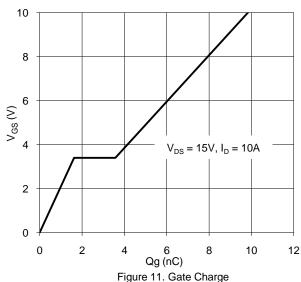


Figure 7. On-Resistance Variation with Temperature





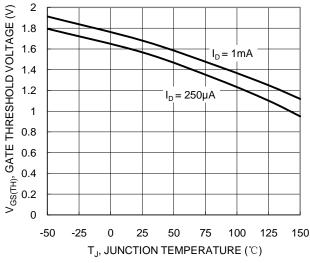
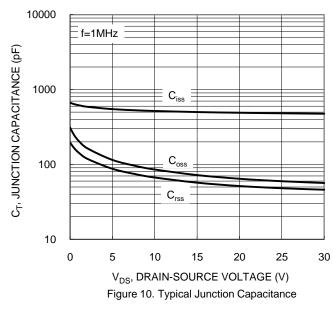
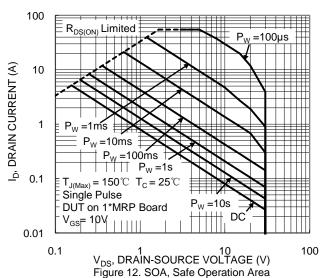


Figure 8. Gate Threshold Variation vs. Junction Temperature





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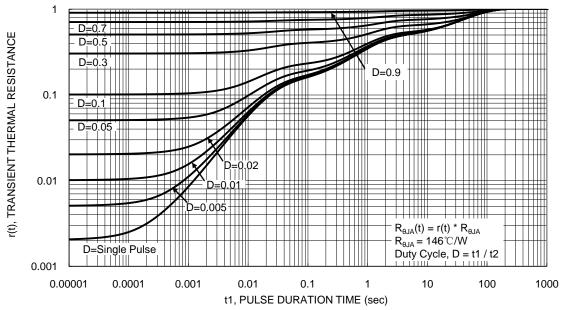


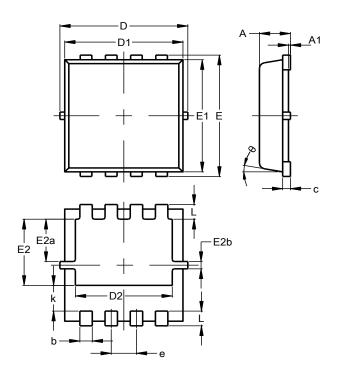
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

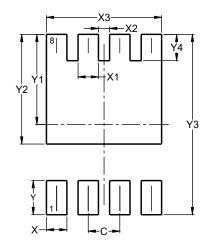


PowerDI3333-8 (Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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